Diode Semiconductor Device - Page 1 of 1



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Inclosure Mater	
Glass	
Overall Length:	
Between 0.230 ir	nches and 0.300 inches
Terminal Length	1:
Between 1.000 ir	iches and 1.500 inches
Overall Diamete	r:
Between 0.092 ir	nches and 0.130 inches
End Application	:
Amcs 82577	
Joint Electronic	Device Engineering Council/jedec/case Outline Designation:
Do-14	
Mounting Metho	bd:
Terminal	
Features Provid	ed:
Hermetically sea	ed case
Semiconductor	Material:
Silicon	
Voltage Rating	n Volts Per Characteristic:
16.0 regulator v	oltage
Current Rating	Per Characteristic:
750.00 milliampe	res forward current, average pascal
Power Rating Po	er Characteristic:
400.0 watts smal	I-signal input power, common-collector preset
Maximum Opera	ating Tempurature Per Measurement Point:
200.0 degrees ce	elsius ambient air
Test Data Docu	nent:
81349-mil-s-1950	00 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specificatio
format; excludes	commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental ar	d performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type A	And Quantity:
2 uninsulated wir	e lead
Specification Da	ata:
81349-mil-s-1950	00/437 government specification
Shelf Life:	
N/a	
Unit Of Measure	
Demilitarization	
No	
Fiig:	
A110a0	